
Low Temperature Bonding by using Nanoporous Gold

Dr. Wei-Shan Wang

Department System Packaging

Fraunhofer Institute for Electronic Nano Systems ENAS



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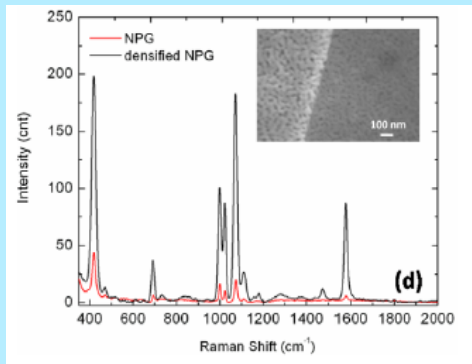
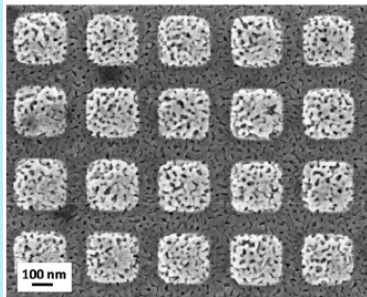
Outline

- Introduction of nanoporous metals
- Low temperature bonding by using nanoporous gold
 - Substrate bonding at low temperature
 - Substrate bonding by using plasma-activated porous gold
 - heterogeneous bonding
- Summary and outlook

Nanostructured Metals

highly active surface area \Rightarrow sensors, actuators, catalysis, packaging...

As SERS Template

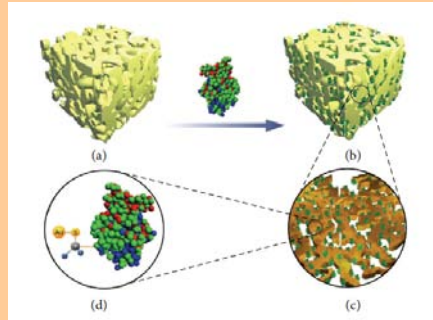


SERS spectra of benzenethiol molecules

Nanotechnology **22**, 295302, 2011

SERS: surface-enhancement
Raman scattering

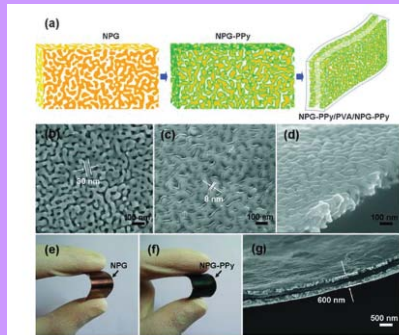
Enzyme-Based Biosensors



Adsorption of lacase on nanoporous Au

J. Phys. Chem. C **112**, 14781, 2008

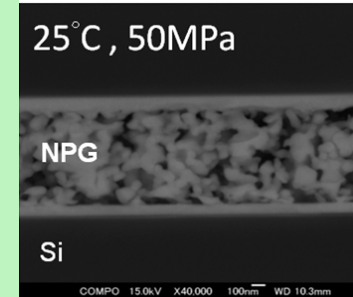
Energy systems



Nanoporous Au for supercapacitors

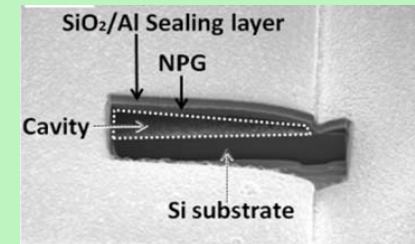
Adv. Mater. **23**, 4098, 2011

Packaging Applications



Low temperature bonding

2012 IEEE Sensors, 355, 2012



Thin film encapsulation

J. Microelec Sys. **12**, 998, 2013

Bonding by using Nanostructured Metals

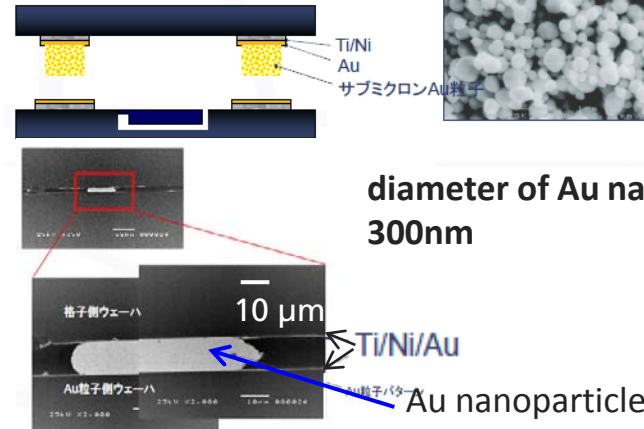
❖ Nano-lawn Au



wire diameter 600nm,
length 1-5 microns

S. Fiedler et al., *IEEE Electron Systeminte.Tech. conference*,
886, 2006.

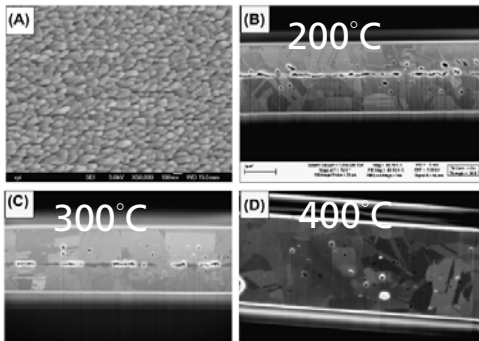
❖ Au nanoparticle



diameter of Au nanoparticle:
300nm

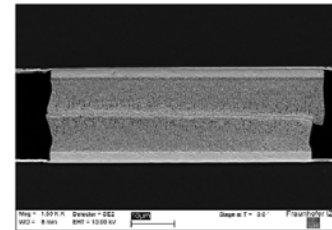
Tanakakinzoku Kogyo K.K. www.tanaka.co.jp

❖ Copper nanorod array



P.I. Wang et.al.,
Electrochemical and Solid-State Letters,
12 4 H138-H141 2009 .
(Rensselaer Polytechnic
Institute, USA)

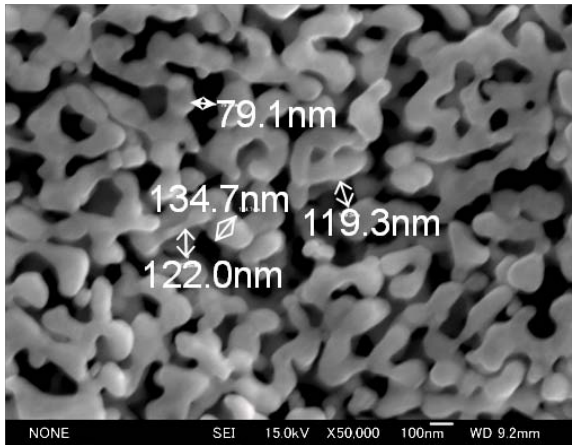
❖ Nanoporous Au bump



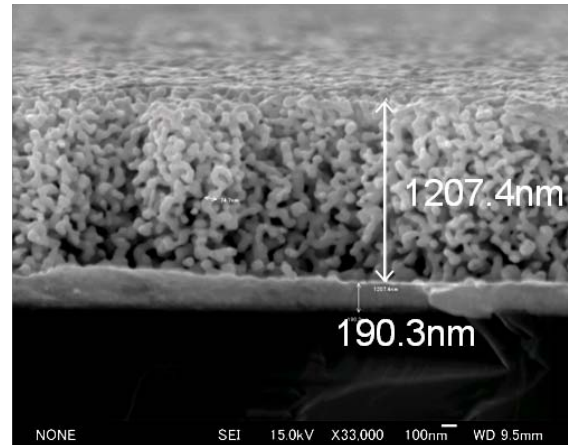
H. Oppermann and L. Dietrich,
Microelectronics Reliability 52,
356, 2012

Structure of Nanoporous Gold

Top view

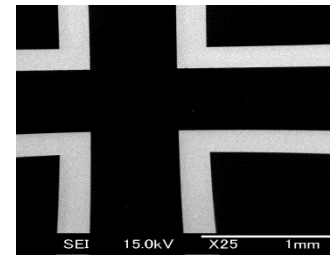
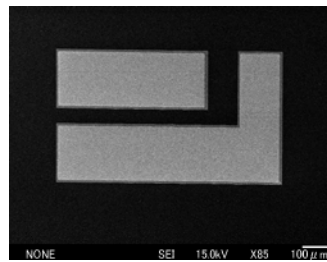
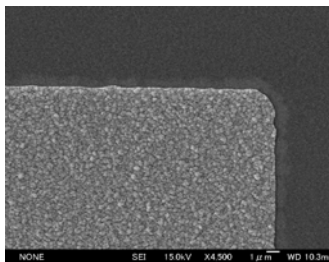


Cross section



- **thickness:**
from hundreds of nm up to several μm
- **porous size:**
around 100nm
- **ligament size:**
up to 100nm

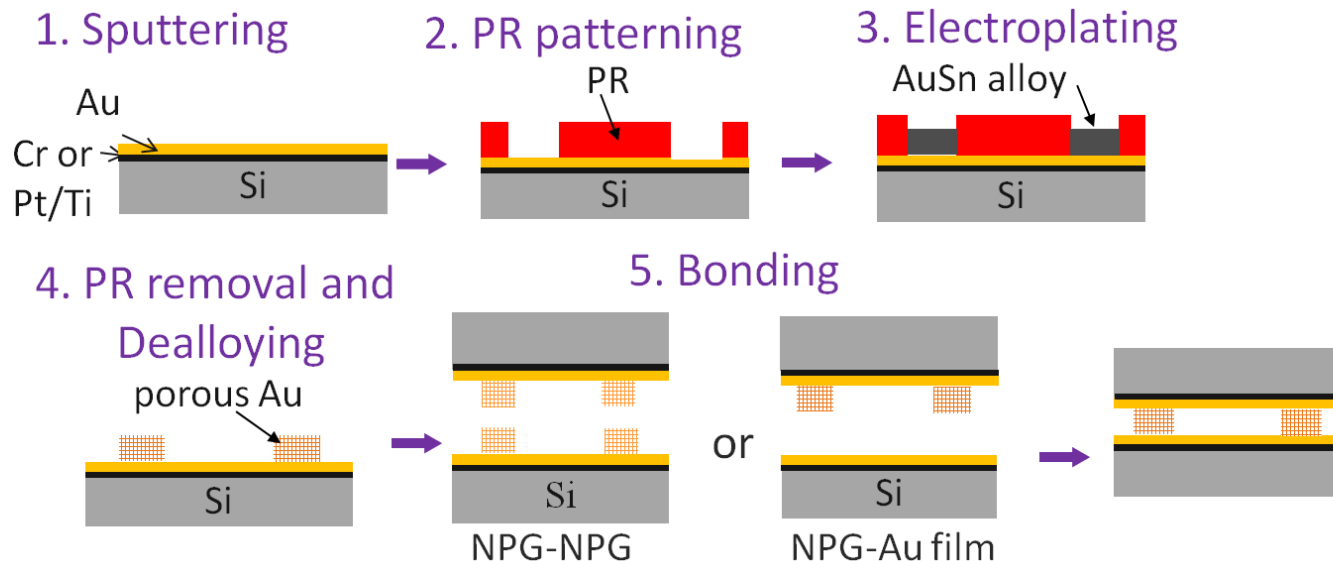
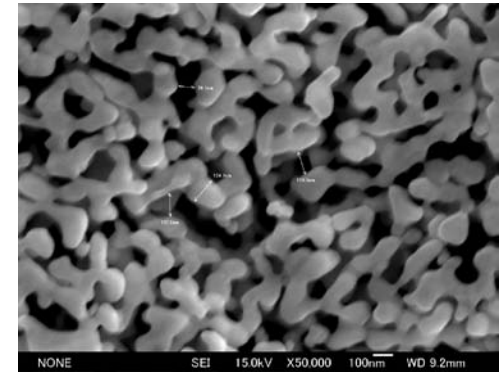
Patterned porous Au



- **pad width:**
40~700 μm
- **frame width:**
100~500 μm

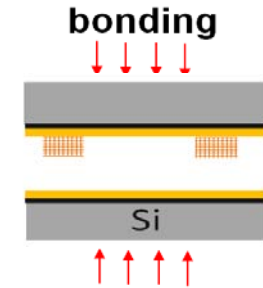
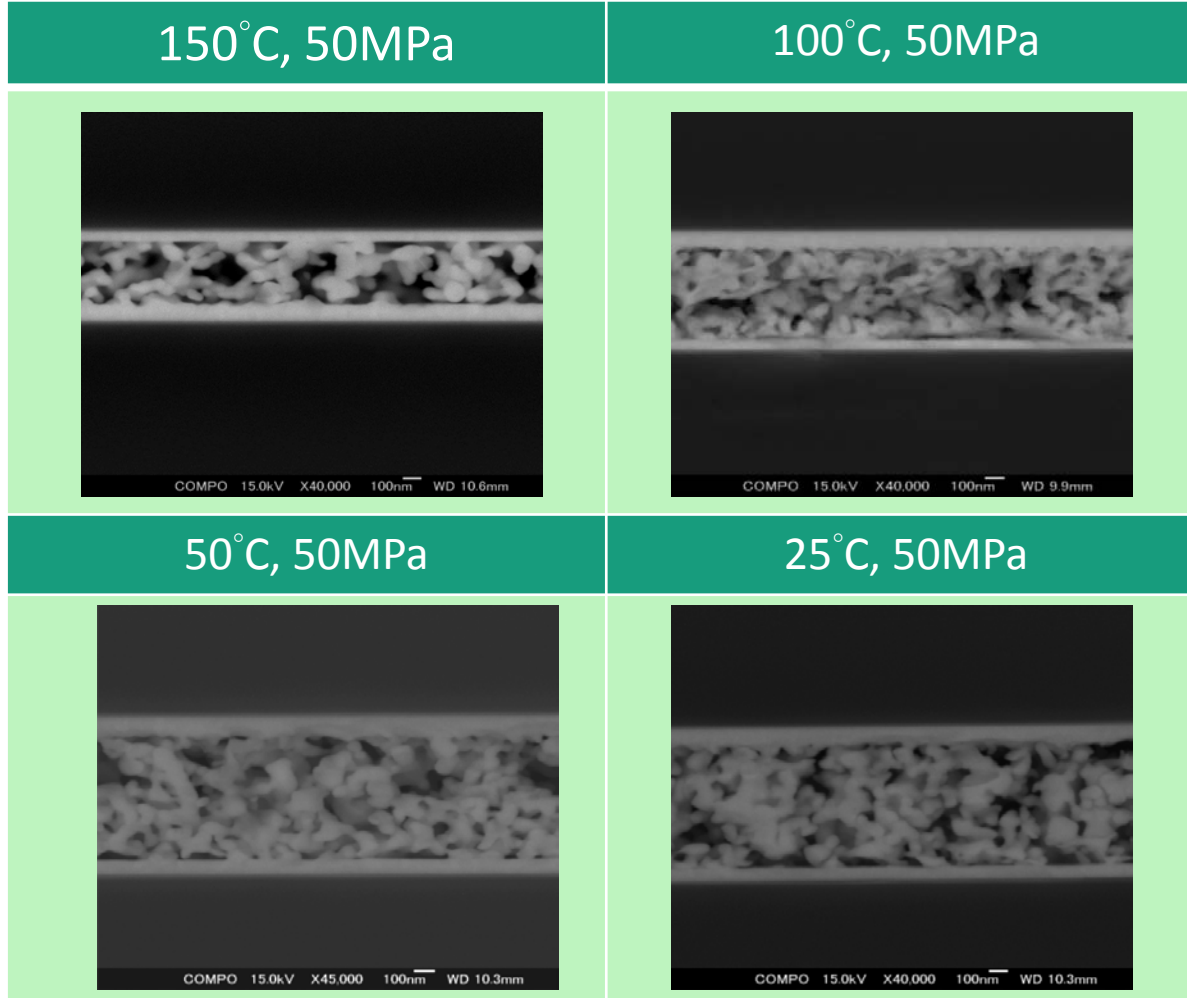
Concept of using Porous Au for Bonding

- High surface to volume ratio
- Low temperature bonding (thermal compression)
- Electrical inter-connection achieved during bonding
- Sponge-like compressibility, tolerate implanarities



Substrate bonding by using plasma-activated NPG

■ bonded at room temperature with plasma-activated NPG



■ **NPG thickness:**

400-800nm, flexible thickness control for bonding

■ **Au thin film:**

200nm

■ **Bonding condition:**

in ambient air

Cooperation - special strengths

JAPAN (Sendai)

Prototype



- Provide key components to systems
- Pioneer leading-edge research
- Open research environment with plenty of home made equipments
- Process by researchers: flexible & novel

Innovation

GERMANY (Chemnitz)

Wafer level



- Smart system integration and reliability
- In preparation for industrially mass production and back end of line
- Latest commercialized equipments including class 10 cleanroom
- Process by technician: professional & stable

Application

Summary and Outlook

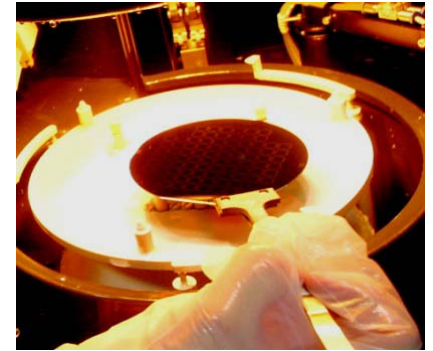
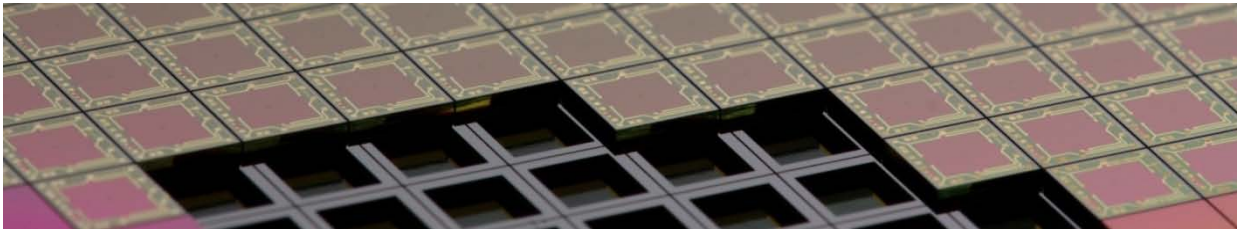
■ Characteristics of Nanoporous Gold

- **MEMS-compatible** fabrication process
- **High surface area:**
 - decrease bonding temperature - down to 200°C or even at room temperature
 - potential candidate for heterogeneous bonding
- **Sponge-like compressibility:**
 - bonding without critical requirements of surface cleanliness and roughness
- **Flexible control of thickness:**
 - bonding achieved regardless of thickness of NPG

■ More Possibilities of Nanoporous Metals

- Advanced materials for packaging
- As catalysts for electrochemical applications
- Biosensors, chemical and physical sensors
- Energy storage/conversion systems

Thank you for your attention



Contact

Dr. Wei-Shan Wang

Fraunhofer ENAS
Department System Packaging

Mail: wei-
shan.wang@enas.fraunhofer.de

Phone: 0371-45001-495

Technologie-Campus-3
09126 Chemnitz
Germany

